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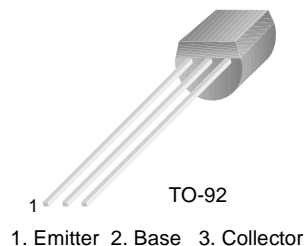
For any questions, you can email us directly:

sales@integrated-circuit.com



KSB1116S

Audio Frequency Power Amplifier & Medium Speed Switching



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	-60	V
V_{CEO}	Collector-Emitter Voltage	-50	V
V_{EBO}	Emitter-Base Voltage	-6	V
I_C	Collector Current (DC)	-1	A
I_{CP}	* Collector Current (Pulse)	-2	A
P_C	Collector Power Dissipation	0.75	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

* $PW \leq 10\text{ms}$, Duty Cycles $\leq 50\%$

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
I_{CBO}	Collector Cut-off Current	$V_{CB} = -60\text{V}, I_E = 0$			-100	nA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = -6\text{V}, I_C = 0$			-100	nA
h_{FE1}	* DC Current Gain	$V_{CE} = -2\text{V}, I_C = -100\text{mA}$	135		600	
h_{FE2}		$V_{CE} = -2\text{V}, I_C = -1\text{A}$	81			
$V_{BE}(\text{on})$	* Base-Emitter On Voltage	$V_{CE} = -2\text{V}, I_C = -50\text{mA}$	-600	-650	-700	mV
$V_{CE}(\text{sat})$	* Collector-Emitter Saturation Voltage	$I_C = -1\text{A}, I_B = -50\text{mA}$		-0.2	-0.3	V
$V_{BE}(\text{sat})$	* Base-Emitter Saturation Voltage	$I_C = -1\text{A}, I_B = -50\text{mA}$		-0.9	-1.2	V
C_{ob}	Output Capacitance	$V_{CB} = -10\text{V}, I_E = 0, f = 1\text{MHz}$		25		pF
f_T	Current Gain Bandwidth Product	$V_{CE} = -2\text{V}, I_C = -100\text{mA}$	70	120		MHz
t_{ON}	Turn On Time	$V_{CC} = -10\text{V}, I_C = -100\text{mA}$ $I_{B1} = -I_{B2} = -10\text{mA}$ $V_{BE}(\text{off}) = 2\sim 3\text{V}$		0.07		μs
t_{STG}	Storage Time			0.7		μs
t_F	Fall Time			0.07		μs

* Pulse Test: $PW \leq 350\mu\text{s}$, Duty Cycles $\leq 2\%$

h_{FE} Classification

Classification	Y	G	L
h_{FE1}	135 ~ 270	200 ~ 400	300 ~ 600

Typical Characteristics

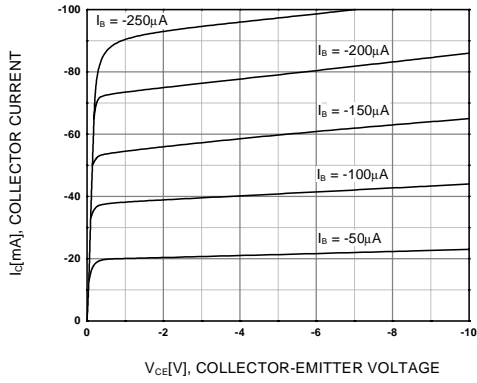


Figure 1. Static Characteristic

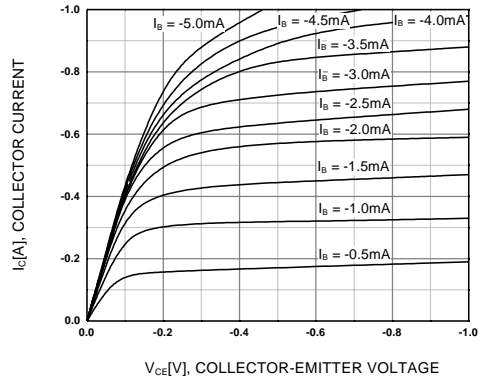


Figure 2. Static Characteristic

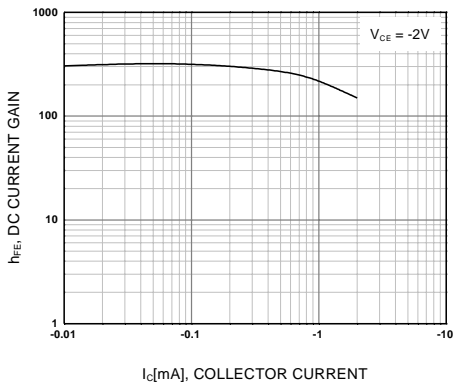
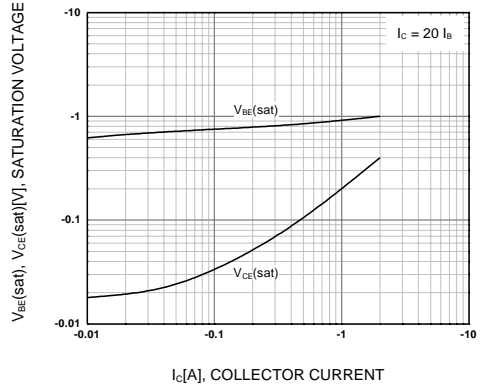


Figure 3. DC current Gain



**Figure 4. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage**

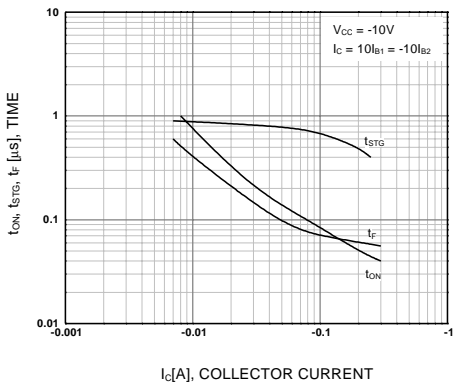


Figure 5. Switching Time

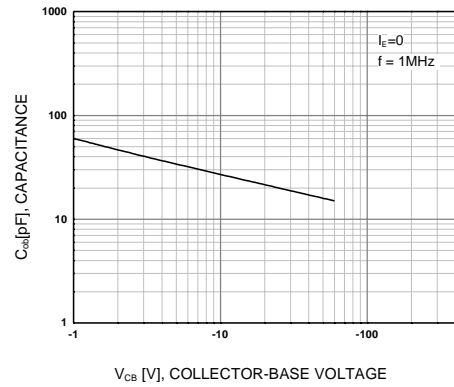


Figure 6. Collector Output Capacitance

Typical Characteristics (Continued)

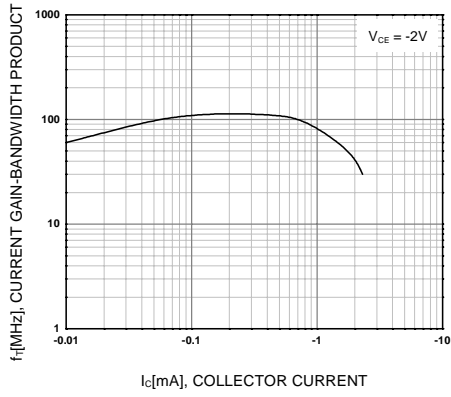


Figure 7. Current Gain Bandwidth Product

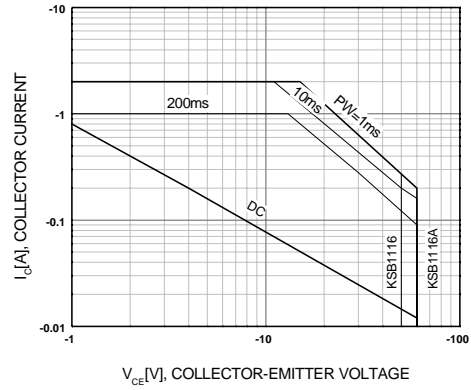


Figure 8. Safe Operating Area

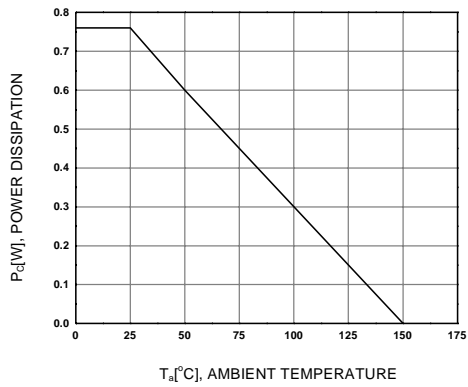
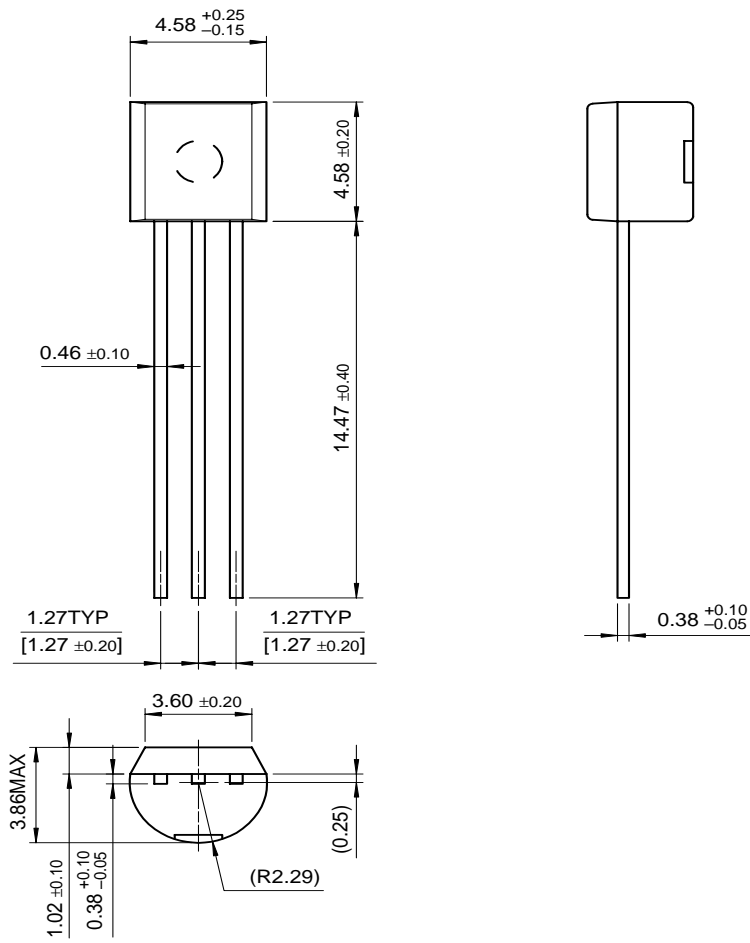


Figure 9. Power Derating

Package Dimensions

TO-92



Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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